

Pin Diode Switch Single Pole 3 Throw Absorptive

AWSP3TA-1M-1GA

Your RF & Microwave Components Source

Features:

- TTL-Compatible Driver
- Broad Operating Bandwidth
- Rugged Construction.
- Customization Is Available

Specifications

Electrical Specifications, TA = +25° C

Parameters	Min.	Тур.	Max.	Units
Frequency Range	1MHz		1GHz	
Insertion Loss			1.5	dB
VSWR			1.5	
Isolation	80			dB
Switching Speed			500	nsec
CW RF Power, Operating			30	dBm
Material	Aluminum			
Finish	Gold Plating			
Input /Output Connector	SMA-Female / SMA-Female (Removable)			

※ Switching speed is defined as 50% TTL to 90% RF (t-on) and 50% TTL to 10% RF (t-off).

Environmental Specifications

45 ~ +85			
55 ~ +125			
25g rms (15 degree 2KHz)			
100% RH at 35c, 95%RH at			
40 deg c			
20G for 11msc			

DC Bias: +5 V±0.5 V @ 150 mA max -5 V±0.5 V @ 50 mA max

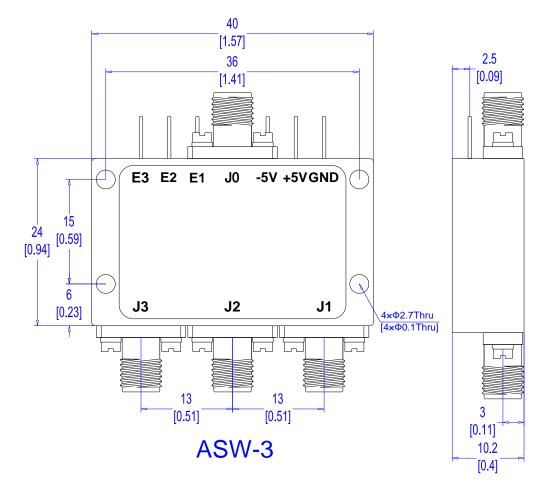
Absolute Maximum Ratings				
Biasing	+5 V ,-5V			
TTL Control Voltage	+5V/0V			
Input RF power	+30dBm			
Storage Temperature (°C)	-55 ~ +125			

The information contained in this document is accurate to the best of our knowledge and representative of the part described herein. It may be necessary to make modifications to the part and/or the documentation of the part, in order to implement improvements. Anway reserves the right to make such changes as required. Unless otherwise stated, all specifications are nominal.

Truth Table

Control Input TTL			Signal Dath State	
E3	E2	E1	Signal Path State	
1	1	0	J0-J1	
1	0	1	J0-J2	
0	1	1	J0-J3	

Outline Drawing:



Dimensions are in MM [inches].

Unless otherwise specified, Outline drawing +/-0.1mm; Hole +/-0.1mm.

	TITLE	Notes: All specifications are subject to change without notice at any			
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